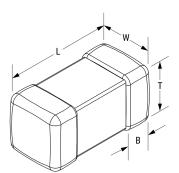


L1210R680KDWIT

Aliases (L1210R680KDWIT)

Not for New Design • Scheduled EOL - Last date to buy 30 JUN 2023

KEMET, L-DWI, Power, 68 uH, 10%



Click here for the 3D model.

Dimensions		/
Chip Size	1210	
L	3.2mm +/-0.2mm	
W	2.5mm +/-0.2mm	
Т	2.5mm +/-0.2mm	
LL	0.6mm +/-0.3mm	
В	0.6mm +/-0.3mm	

Packaging Specifications		
Packaging	T&R	
Packaging Quantity	1000	

General Information		
Series	L-DWI	
Style	SMD Chip	
Description	Surface Mount Inductor	
Features	High Current Type	
RoHS	Yes	
Notes	Last Order Date June 30, 2023. Suggested Replacement - https://productfinder.pulseelectronics.com/part/BWNC00372926680K00.	

Specifications	
Inductance	68 uH (0.1 MHz)
Inductance Tolerance	10%
Temperature Range	-40/+105°C
Current	320 mAmps (Isat, 30% Drop In Inductance), 410 mAmps (Irms, 40C Rise By Self Heating)
DC Resistance	10hms
Self-Resonant Frequency	8 MHz

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.